



# Modification of emission properties of ZnO layers due to plasmonic near-field coupling to self-organized Ag nanoislands

J. Papierska<sup>1</sup>, B. S. Witkowski<sup>2</sup>, A. Derkachova<sup>2</sup>,  
K. P. Korona<sup>1</sup>, J. Binder<sup>1</sup>, K. Gałkowski<sup>1</sup>,  
Ł. Wachnicki<sup>2</sup>, M. Godlewski<sup>2</sup>, T. Dietl<sup>1,2</sup>, and  
J. Suffczyński<sup>1</sup>

<sup>1</sup> Faculty of Physics, University of Warsaw, Warsaw, Poland

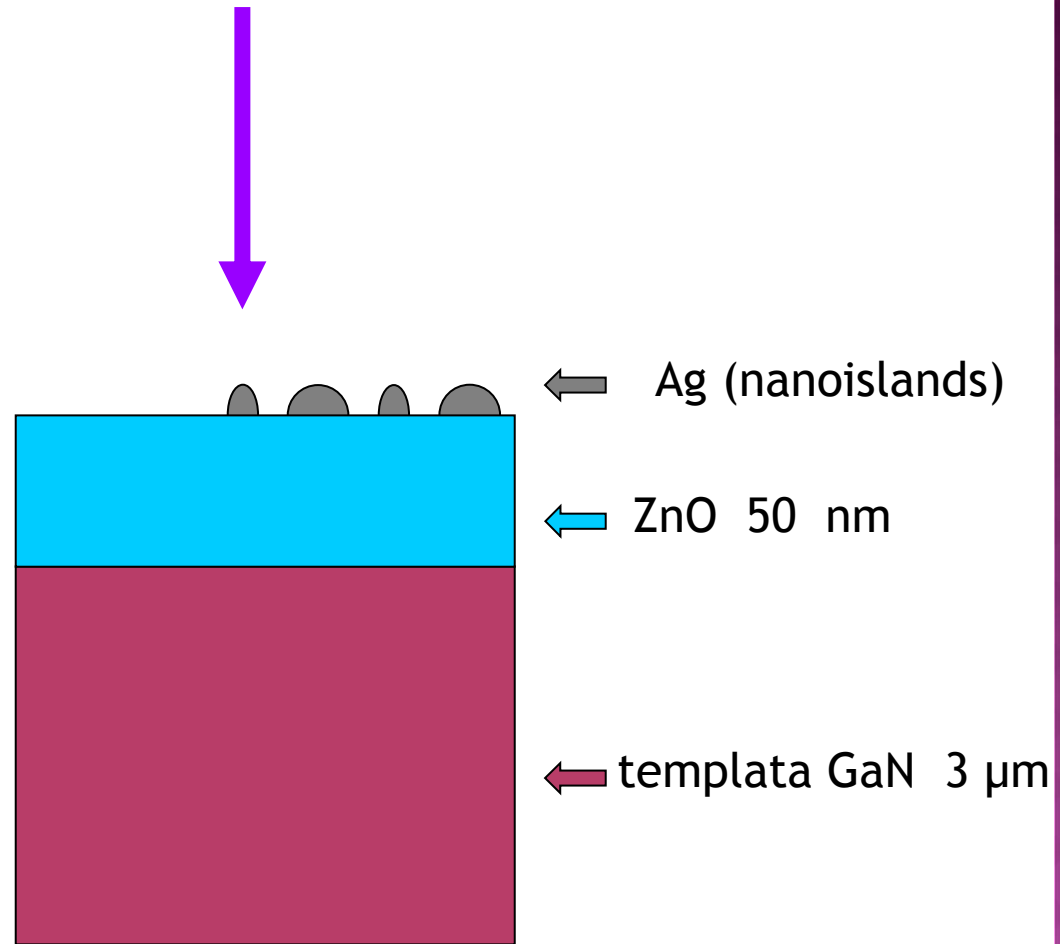
<sup>2</sup> Institute of Physics, Polish Academy of Sciences, Warsaw, Poland

1. Samples
2. Scanning electron microscope (SEM)
3. Experiment
4. Photoluminescence (PL)
5. Time-resolved PL (TRPL)
6. Theoretical model
7. Conclusions
8. Plan

Ag nanoislands  
self-organized  
plasmonic

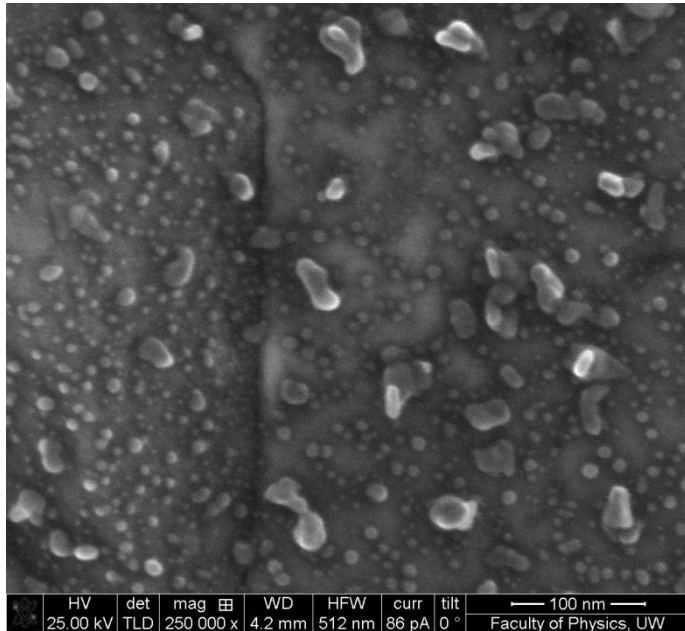
➤ **sample A:**  
covered with silver islands by sputter deposition lasting for 2 s

➤ **sample B:**  
coated by Ag sputtering over 15-20 s, yielding a 3 nm layer of Ag, and then annealed at temperature of 750°C for 3 min



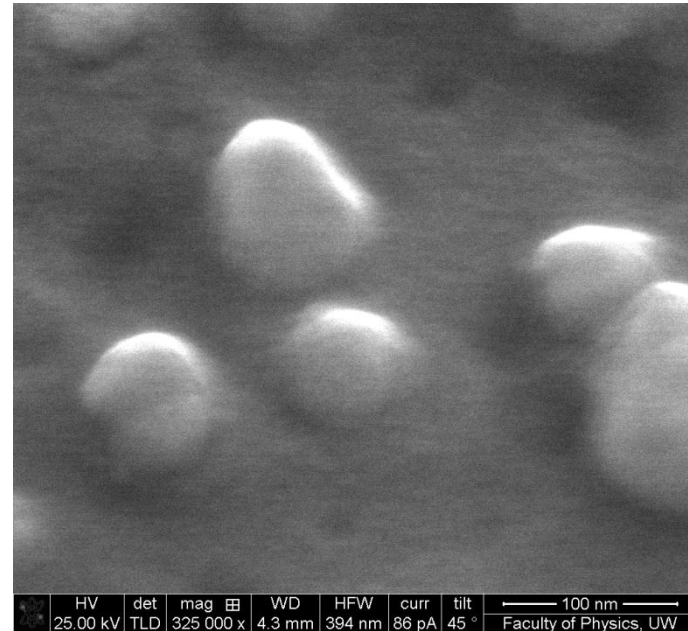
atomic layer deposition (ALD) method

Sample A



diameter  $D = 10\text{-}40$  nm  
surface density  $\rho \approx 2000/\mu\text{m}^2$

Sample B



diameter  $D = 70\text{-}100$  nm  
surface density  $\rho \approx 25/\mu\text{m}^2$

The Ag islands have a quasi-spherical shape in both samples.

➤ **Photoluminescence (PL)**

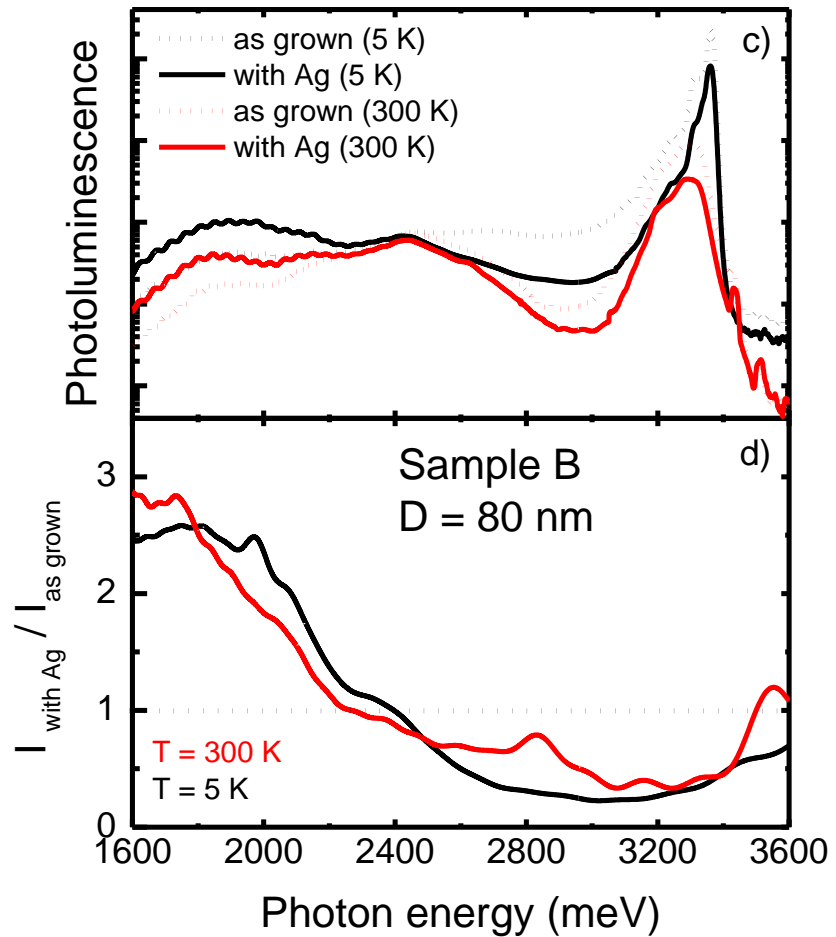
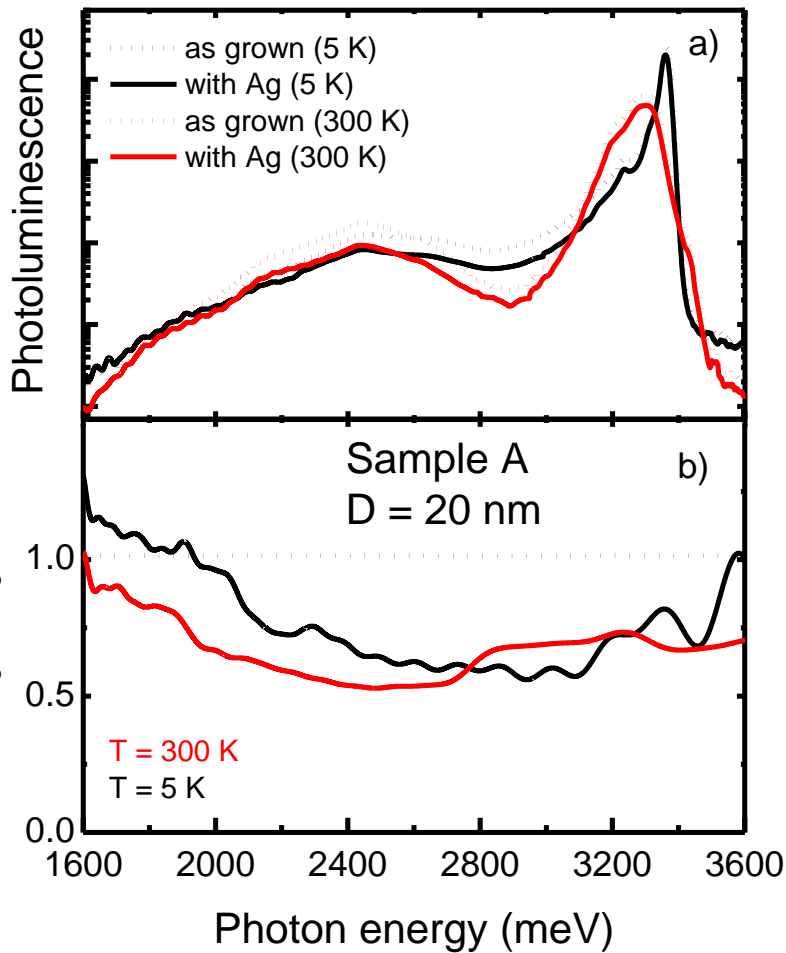
- emission excited at 325 nm (3.81eV) (He-Cd laser)
- at 5 K and 300 K
- a grating monochromator (600 gr/mm or 1800 gr/mm)
- CCD camera

➤ **Time-Resolved PL (TRPL)**

- emission excited at 300 nm (4.1eV) (frequency tripled Ti:Sapp pulsed laser)
- at 4 K
- a grating monochromator (600 gr/mm or 1800 gr/mm)
- a streak camera

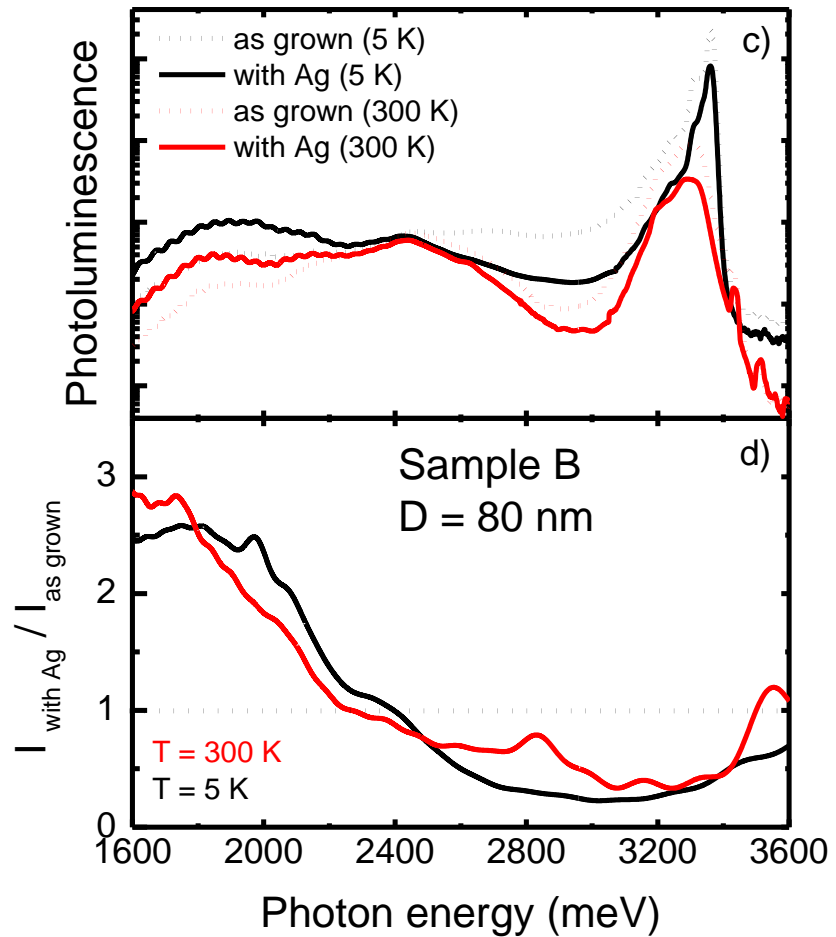
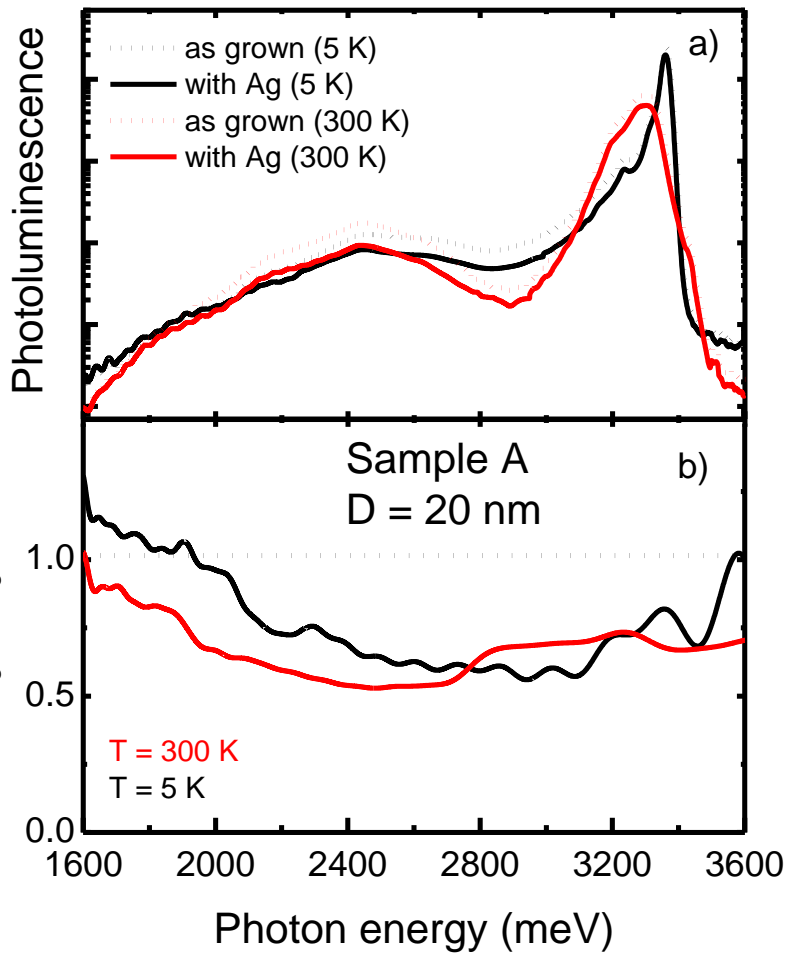
➤ **Transmission**

- a halogen lamp as the light source
- at 300 K
- a grating monochromator (600 gr/mm or 1800 gr/mm)
- CCD camera

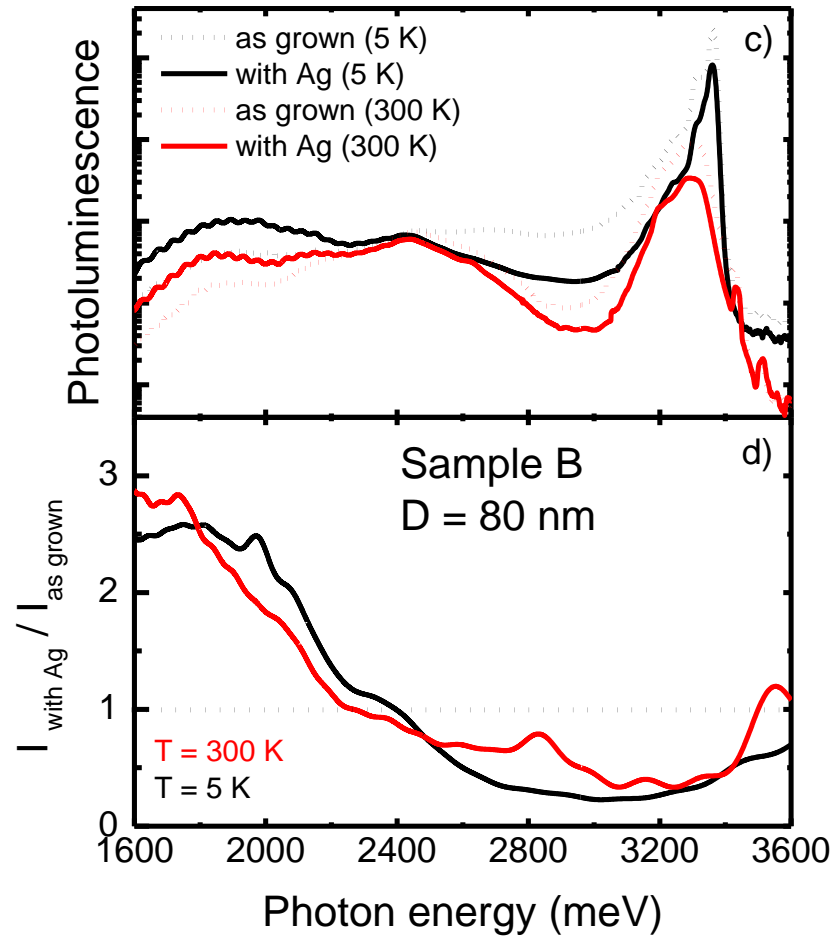
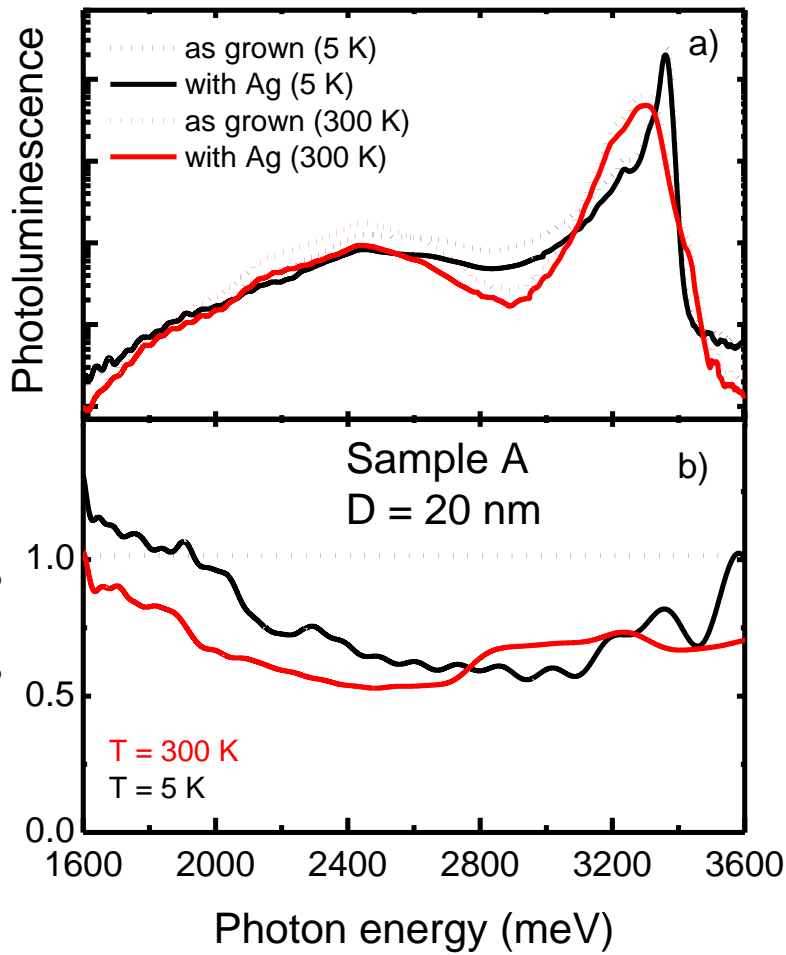


- optical transitions:
  - ✓ ~3.36 eV → bound exciton emission in ZnO
  - ✓ 2.90-3.33 eV → stacking faults
  - ✓ below ~2.9 eV → a weak defect
- temperature increase → a shift towards lower energies and broadening





- sample A (10-20 nm Ag islands)
- ✓ slight PL decrease in the almost entire spectral range
  
- sample B : (80-90 nm Ag islands)
- ✓ enhancement of the emission → below ~2.4 eV
- ✓ a quenching of the emission → above ~2.4 eV

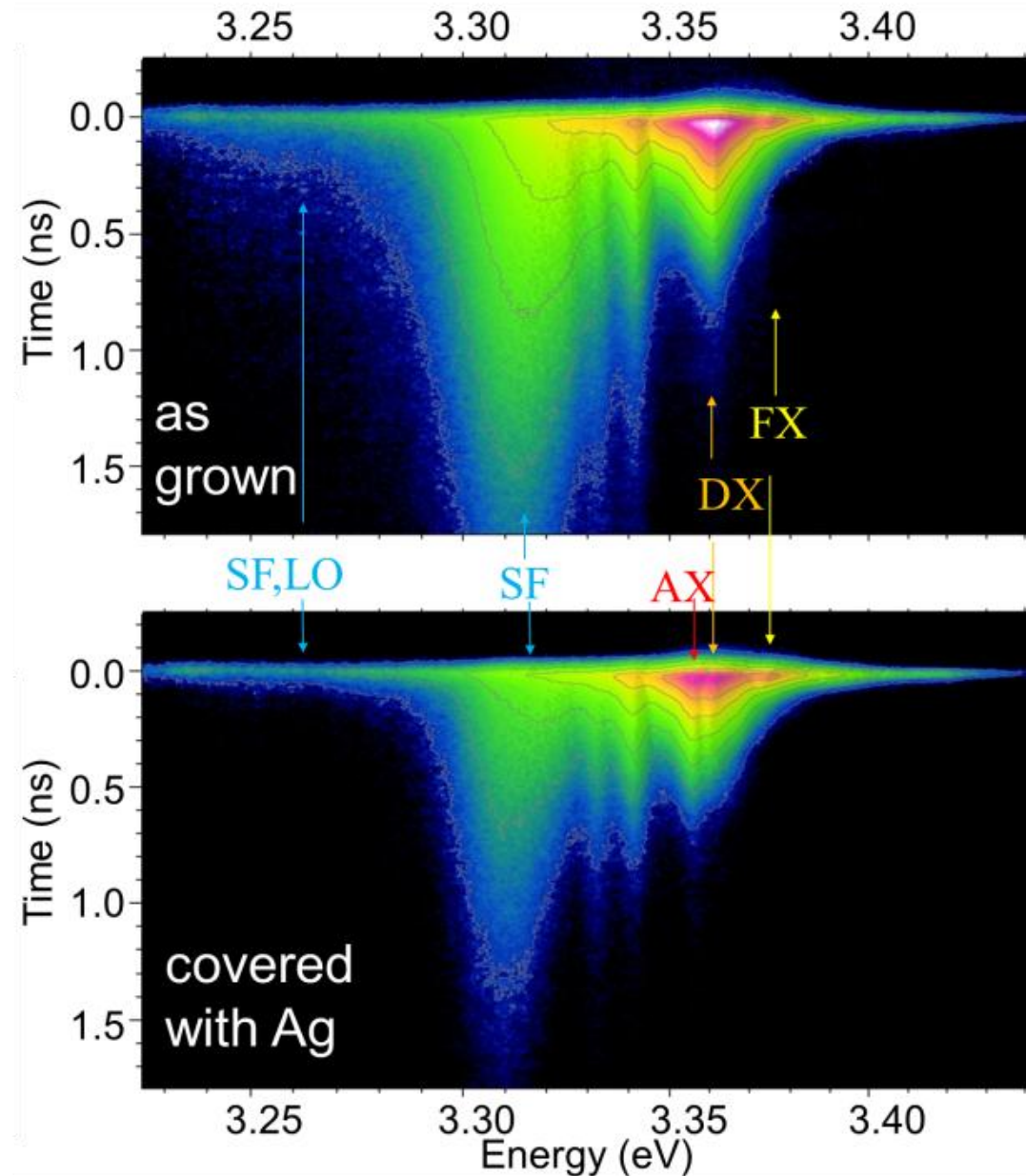


enhancement or quenching are independent of temperature & magnitude of electron density independent of temperature → plasmonic effects in Ag



## Sample B

## Transmission:



- free exciton (FX) → 3.375 eV
- donor bound exciton (DX) → 3.361 eV
- two weak peaks → 3.33 eV and 3.34 eV
- stacking fault (SF) → 3.30 – 3.33 eV
- acceptor bound exciton (AX) → 3.356 eV (not observed in the signal from the uncovered sample) → the diffusion of the Ag atoms, acting as acceptor centers, to ZnO layer during the process of the sample annealing

Transition		FX	DX	SF
Energy (eV)		3.375	3.36	3.30 - 3.33
PL lifetime (ps) (fast components)	as grown	35(5)	77(5)	40(15)
	with Ag	25(5)	66(5)	30(10)
Intensity ( $10^3$ counts)	as grown	4.7	39	7.0
	with Ag	4.0	17	1.3

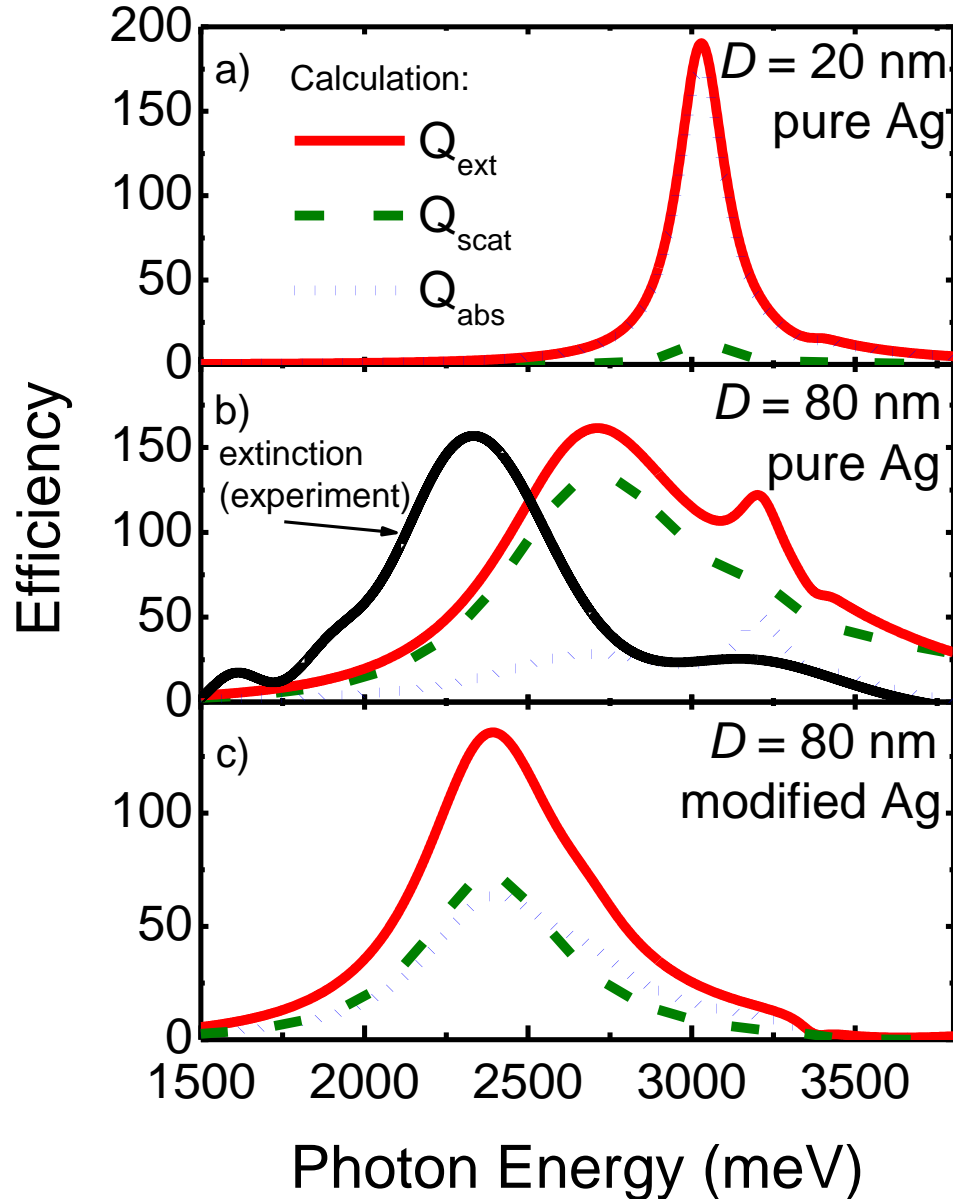
- large Ag nanoislands → reduced decay times and emission intensity → the existence of additional nonradiative channel related to the coupling of the emission to surface plasmons confined in the Ag nanoislands
- small Ag nanoislands have a minor effect on the PL lifetimes

Mie scattering theory:

- the efficiencies  $Q_{\text{scat}}$ ,  $Q_{\text{ext}}$ ,  $Q_{\text{abs}}$  of scattering, extinction and absorption
  - light interacting with a single spherical particle of a radius  $R$
  - the dielectric function of silver as in the classical Drude model
- 
- ✓ Sample A: dielectric function of pure silver  
 $\epsilon_{\text{ib}} = 3.7$ ,  $\gamma_{\text{bulk}} = 0.18 \text{ eV}$ ,  $\omega_{\text{p}} = 9.1 \text{ eV}$
  - ✓ Sample B: annealing at temperature of  $750^\circ\text{C}$  → interdiffusion of Ag and Zn → the effective parameters modified  
 $\epsilon_{\text{ib}} = 8.1$ ,  $\gamma_{\text{bulk}} = 0.3 \text{ eV}$ ,  $\omega_{\text{p}} = 9.1 \text{ eV}$

$n_{\text{ZnO}}$  → following A. B. Djurišić et al., Appl. Phys. A, **43**, 37 (2003)

$$n_{\text{out}} = f n_{\text{Air}} + (1 - f) n_{\text{ZnO}}$$

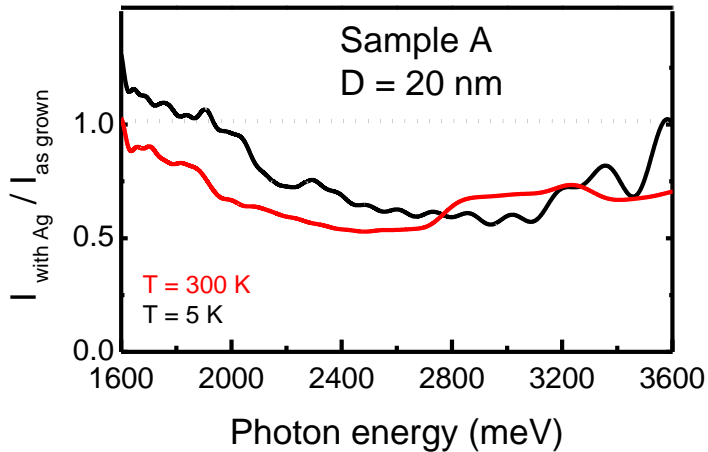
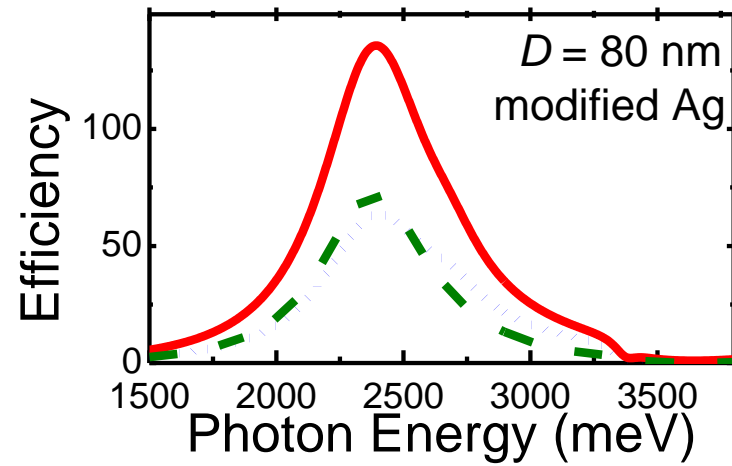
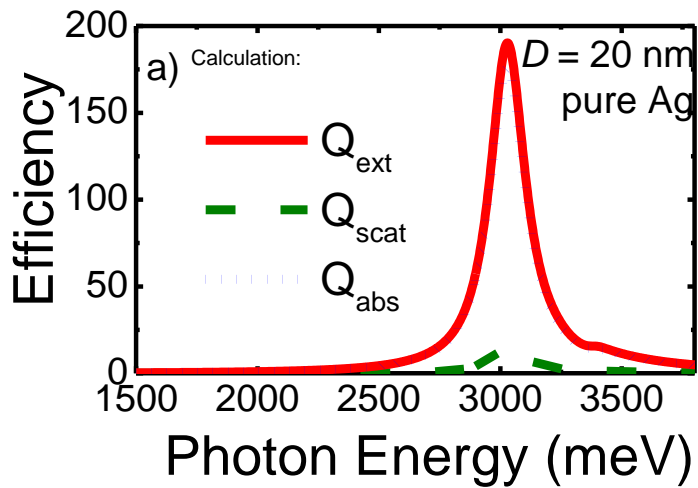


➤ the extinction maximum shifts to lower energies when the radius of the sphere increases:

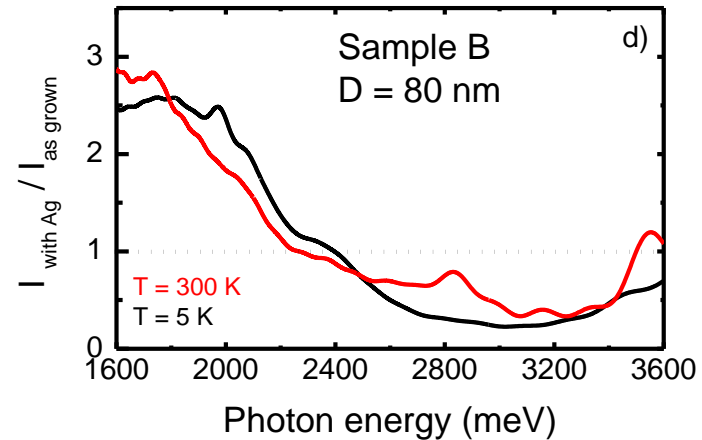
✓ sample A:  $D = 10$ - $20$  nm  
 → energy of extinction maximum  $\sim 3$  eV

✓ sample B:  $D = 80$ - $90$  nm  
 → energy of extinction maximum  $\sim 2.7$  eV or  $\sim 2.4$  eV

➤ increase of the sphere radius → a decrease of the absorption efficiency and an enhancement of the scattering efficiency



- Sample A : the absorption dominates over the scattering in the whole studied spectral range → a decrease of the PL intensity



- Sample B:
- the absorption dominates over the scattering above 2.5 eV → a quenching of the emission
  - scattering dominates over the absorption → below ~2.5 eV emission enhancement

- The fabrication process, involving sputtering and annealing, has served to obtain Ag nanoislands of dimensions insuring the presence of the strong plasmonic effects.
- The temperature independent enhancement or quenching of the emission is observed and explained by the numerical model developed within the Mie theory.
- The ratio of the absorption to scattering efficiencies is found to govern the emission enhancement or quenching.
- The model highlights the impact of the sample preparation on the dielectric function of Ag.

➤ **QD CdTe/ZnTe** → MBE University of Warsaw → VIS

➤ **QW GaN/AlGaN** → MBE UNIPRESS and MOVPE University of J.Kepler Linz → UV:

- Porosity of the surface (UNIPRESS)
- Sputtering (islands) and lithographically defined metal nanostructures → Au, Ag, Al.
- variable distance from the surface to the emitter → optimal distance (strong plasmonic mode intensity and small intensity of nonradiative process )